

P180FP6SN

Power MOSFETs 60V, 180A, N-channel

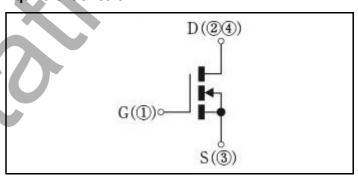
Feature

- N-channel
- SMD
- Large Current
- Low Ron
- 10V Gate Drive
- Low Capacitance
- · Pb free terminal
- RoHS:Yes

OUTLINE



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperrature	Tstg	•	-55 to 175	°C
Channel tempertature	Tch		-55 to 175	°C
Drain-source voltage	V_{DSS}		60	V
Gate-source voltage	V_{GSS}		±20	V
Continuous drain current(DC)	I _D		180	Α
Continuous drain current(Peak)	I _{DP}	Pulse width 10µs, duty=1/100	720	Α
Total power dissipation	P _T		238	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch≦150°C	75	Α
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch≦150°C	600	mJ

^{* :} See the original Specifications

Electrical Characteristics (unless otherwise specified : Tc=25°C)

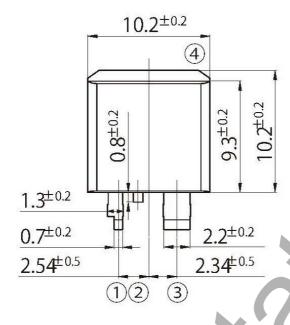
Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	Onit
Drain-Source breakdown voltage	V _{(BR)DSS}	ID=1mA, VGS=0V	60			V
Zero gate voltage drain current	I _{DSS}	VDS=60V, VGS=0V			1	μΑ
Gate-source leakage current	I _{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	9 _{fs}	ID=90A, VDS=10V	40	80		S
Static drain-source on-state resistance	R _{DS(ON)}	ID=90A, VGS=10V		0.0016	0.002	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V _{SD}	IS=180A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case			0.63	°C/W
Total gate charge	Qg	VDD=48V, VGS=10V, ID=180A		158		nC
Gate to source charge	Qgs	VDD=48V, VGS=10V, ID=180A		45		nC
Gate to drain charge	Qgd	VDD=48V, VGS=10V, ID=180A		75		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		9380		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		570		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		1190		pF
Turn-on delay time	td(on)	ID=90A, RL=0.33Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		14		ns
Rise time	tr	ID=90A, RL=0.33Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		79		ns
Turn-off delay time	td(off)	ID=90A, RL=0.33Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		96		ns
Fall time	tf	ID=90A, RL=0.33Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		48		ns
Diode reverse recovery time	trr	IF=180A, VGS=0V, di/dt=100A/μs		65		ns
Diode reverse recovery charge	Qrr	IF=180A, VGS=0V, di/dt=100A/μs		124		nC

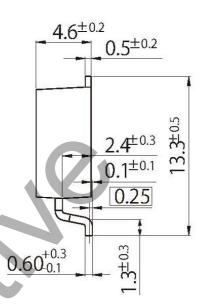
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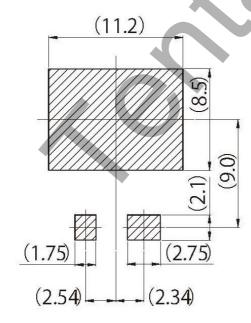
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H5

JEDEC Code	_		
JEITA Code	SC-83 similar		
House Name	FP		







- ・量産時には、適正化を図って下さい
- Optimize soldering pad to the board design and soldering condition.

Notes

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(Special applications)

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